PHAROS



Modular-Design Femtosecond Lasers for Industry and Science

FEATURES

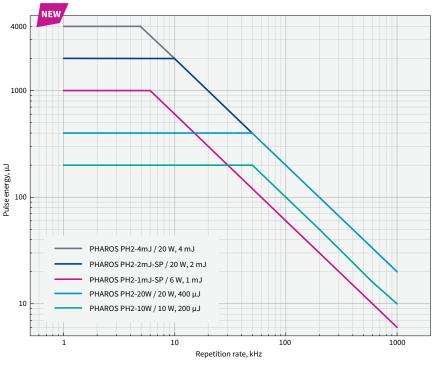
- Tunable pulse duration, 100 fs 20 ps
- Maximum pulse energy of up to 4 mJ
- Down to < 100 fs right at the output
- Pulse-on-demand and BiBurst for pulse control
- Up to 5th harmonic or tunable extensions
- CEP stabilization or repetition rate locking
- Thermally-stabilized and sealed design



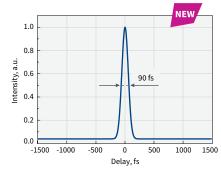
PHAROS is a series of femtosecond lasers combining multi-millijoule pulse energy and high average power. PHAROS features a mechanical and optical design optimized for both scientific and industrial applications. A compact, thermally-stabilized, and sealed design enables PHAROS integration into various optical setups and machining workstations. The robust optomechanical design provides an exceptional laser lifetime and stable operation in varying environments.

The tunability of PHAROS allows the system to cover applications normally requiring multiple different laser systems. Tunable parameters include pulse duration (100 fs – 20 ps), repetition rate (single-shot – 1 MHz), pulse energy (up to 4 mJ), and average power (up to 20 W).

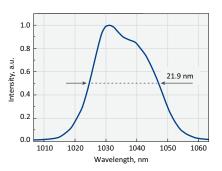
A pulse-on-demand mode is available using the built-in pulse picker. The versatility of PHAROS can be extended by a variety of options, including carrier-envelope phase (CEP) stabilization, repetition rate locking to an external source, automated harmonic modules and optical parametric amplifiers.



Pulse energy vs fundamental repetition rate of PHAROS



Typical pulse duration of PHAROS-PH2-UP



Typical spectrum of PHAROS-PH2-UP



SPECIFICATIONS

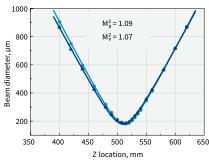
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Model 1)		PH2-10W	PH2-20W	PH2-4mJ	PH2-1mJ-SP	PH2-2mJ-SP	PH2-UP
OUTPUT CHARACTERIST	IC						
Maximum output power		10 W		20 W	10 W	20 W	10 W / 20 W
Pulse duration 2)		< 290 fs		< 450 fs ³⁾	< 190 fs		< 100 fs
Pulse duration tuning range		290 fs – 10 ps (20 ps on request)		450 fs – 10 ps	190 fs – 10 ps (20 ps on request)		100 fs – 10 ps
Maximum pulse energy		0.2 mJ / 0.4 mJ		4 mJ	1 mJ	2 mJ	0.2 mJ / 0.4 mJ
Repetition rate		Single-shot – 1 MHz					
Pulse selection		Single-shot, pulse-on-demand, any fundamental repetition rate division					
Center wavelength 4)		1030 ± 10 nm					
Polarization				Linear,	horizontal		
Beam quality, M ²		< 1.2		< 1.3			< 1.2
Beam diameter 5)		3.3 ± 0.4 mm	/ 4 ± 0.4 mm	6.6 ± 0.7 mm	4.5 ± 0.5 mm	6.6 ± 0.7 mm	4.5 ± 0.5 mm
Beam pointing stability		< 20 μrad/°C					
Pre-pulse contrast		<1:1000					
Post-pulse contrast		<1:200					
Pulse-to-pulse energy stability 6)		< 0.5% RMS deviation ⁷⁾ over 24 h					
Long-term power stability 6)		< 0.5% RMS deviation ⁷⁾ over 100 h					
MAIN OPTIONS							
Oscillator output		1 – 6 W, 50 – 250 fs, ≈ 1035 nm, ≈ 76 MHz ⁸⁾					
Harmonic generator 9)		515 nm, 343 nm, 257 nm, or 206 nm; see page 18					
Optical parametric amplifier 10)		320 – 10000 nm; see page 26					
BiBurst option		Tunable GHz and MHz burst with burst-in-burst capability; see page 13					
CEP stabilization		See page 9					
Repetition rate locking					риде 9 		
PHYSICAL DIMENSIONS							
Laser head (L × W × H) 11)		730 × 419	× 230 mm	843 × 492 × 250 mm		730 × 419 × 230 mr	n
Chiller (L × W × H)				590 × 484 × 267 mm			
24 V DC power supply (L ×)	W × H) ¹¹⁾			280 × 14	14 × 49 mm		
ENVIRONMENTAL & UTIL	ITY REQU	IREMENTS					
Operating temperature		15–30 °C (air conditioning recommended)					
Relative humidity		< 80% (non-condensing)					
Electrical requirements	Laser	100 V AC, 12 A – 240 V AC, 5 A, 50 – 60 Hz					
	Chiller	100 – 230 V AC, 50 – 60 Hz					
Rated power	Laser	1000 W					
	Chiller	1400 W					

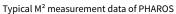
- 1) More models are available on request.
- Assuming Gaussian pulse shape.
- Pulse duration can be reduced to < 250 fs if pulse peak intensity of > 50 GW/cm² is tolerated by customer setup.
- ⁴⁾ Precise wavelengths for specific models are available on request.
- FW 1/e², measured at laser output, using maximum pulse energy.
- ⁶⁾ Under stable environmental conditions.
- 7) Normalized to average pulse energy, NRMSD.
- 8) Available simultaneously. Contact sales@lightcon. com for details or customized solutions
- Integrated. For external harmonic generator, refer to HIRO.
- 10) Integrated. For -4mJ and -UP models, as well as external OPAs, refer to ORPHEUS OPAs.
- ¹¹⁾ Dimensions depend on laser configuration and integrated options.

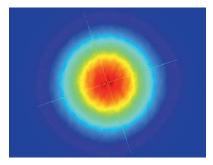




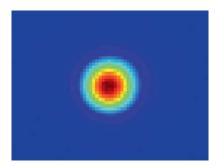
BEAM PROPERTIES





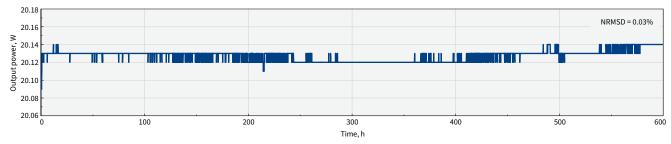


Typical near-field beam profile of PHAROS



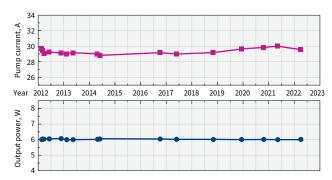
Typical far-field beam profile of PHAROS

STABILITY MEASUREMENTS

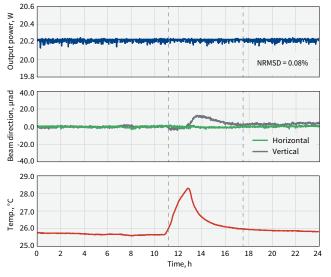


Long-term power stability of PHAROS

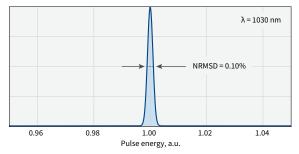




Output power of industrial-grade PHAROS lasers operating 24/7 and current of pump diodes during the years



PHAROS output power and beam direction with power lock enabled, under varying environmental conditions

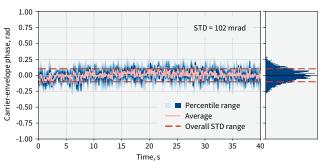


Typical pulse-to-pulse energy stability



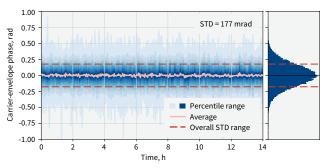
CEP STABILIZATION

PHAROS lasers can be equipped with feedback electronics for carrier-envelope phase (CEP) stabilization of the output pulses. The carrier-envelope offset (CEO) of the PHAROS oscillator is actively locked to 1/4th of the repetition rate with a < 100 mrad standard deviation. The CEP stable pulses



Short-term CEP stability of PHAROS operating at 200 kHz repetition rate

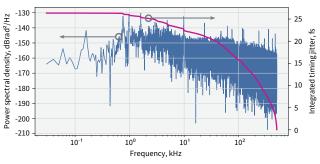
from the synchronized amplifier have a < 350 mrad standard deviation. The CEP drift occurring inside the amplifier and the user's setup can be compensated with an out of loop f-2f interferometer, which is a part of the complete PHAROS active CEP stabilization package.



Long-term CEP stability of PHAROS operating at 200 kHz repetition rate

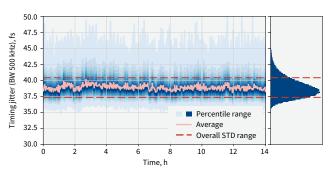
REPETITION RATE LOCKING

The oscillator of PHAROS laser can be customized for repetition rate locking applications. Coupled with the necessary feedback electronics, the repetition rate is synchronized to an external RF source using the two piezo stages installed inside the cavity.



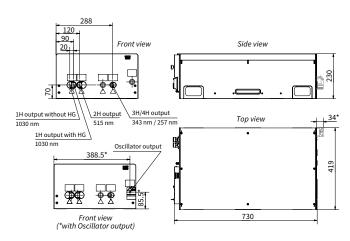
Phase noise data of PHAROS oscillator locked to a 2.8 GHz RF source

The repetition rate locking system can assure an integrated timing jitter of less than 200 fs for RF reference frequencies larger than 500 MHz. Continuous phase shifting is available on request.

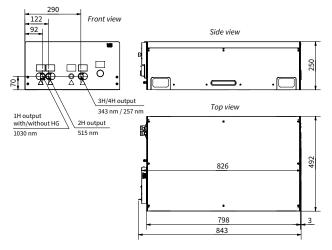


Timing jitter stability over 14 h; PHAROS oscillator locked to a 2.8 GHz RF source

DRAWINGS



PHAROS-PH2 drawing



PHAROS-PH2-4mJ drawing